

Lab #3

Transparent Conductors

R.J. Ellingson and M.J. Heben

Sept. 23, 2014

PHYS 4580, 6/7280

TODAY AT 4:30 PM, R1 ROOM 1010

Special Colloquium
UT Wright Center for PVIC/SSARE



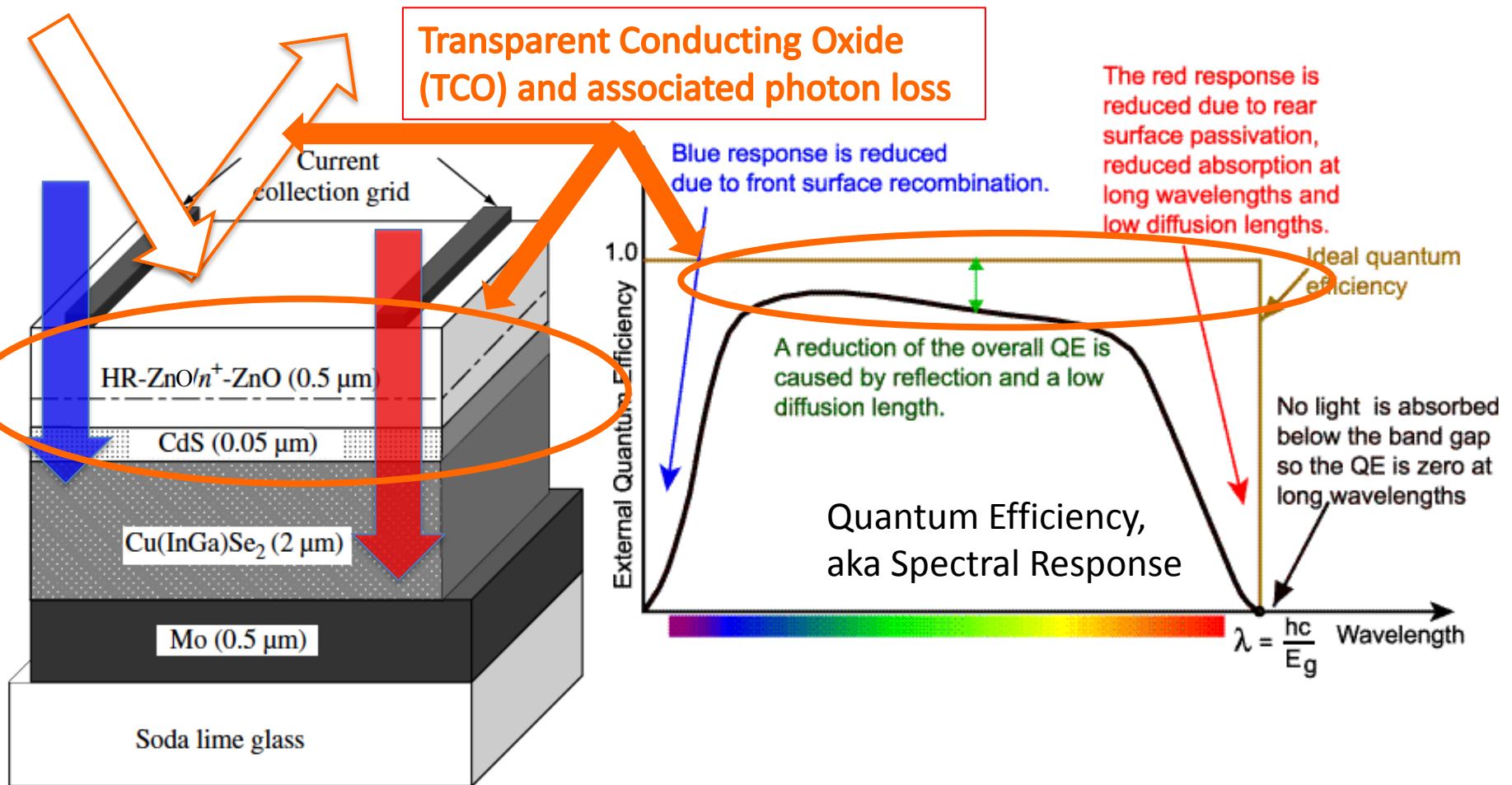
**Photovoltaic Performance and Reliability at
the Module Scale**

Dr. Timothy Silverman

National Renewable Energy Laboratory

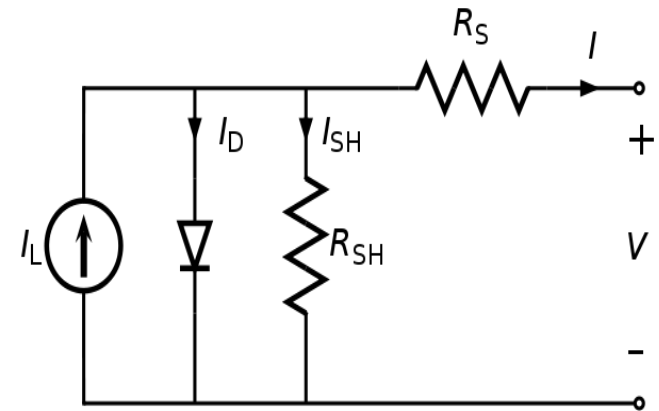
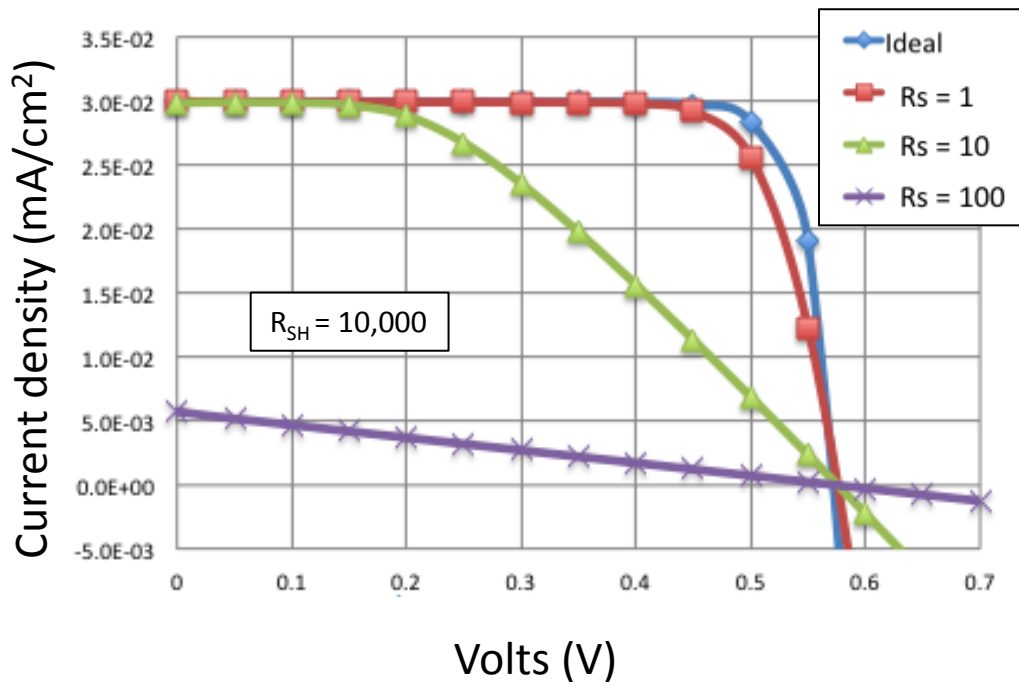
The presentation will summarize results from four different studies in PV performance and reliability, highlighting issues that emerge at the module scale. Topics to be discussed include the apparently positive P_{mp} temperature coefficient for thin-film GaAs modules, challenges associated with achieving performance stabilization for polycrystalline thin-film PV modules without light, the development of mechanical loading as a fast substitute for thermal cycling to determine the susceptibility to broken ribbons in crystalline Si modules, and the progress toward developing the capability for predicting failure due to nonuniform devices and illumination.

Impact of Optical Loss in Window Layer in PV Cells



Schematic cross section of a typical Cu(InGa)Se₂ solar cell

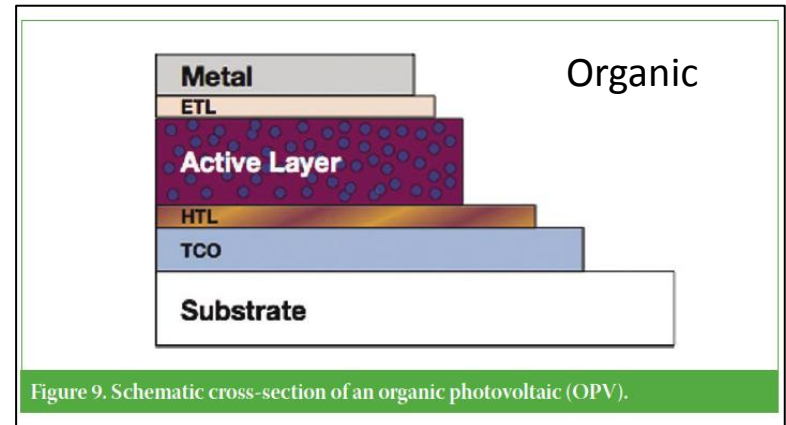
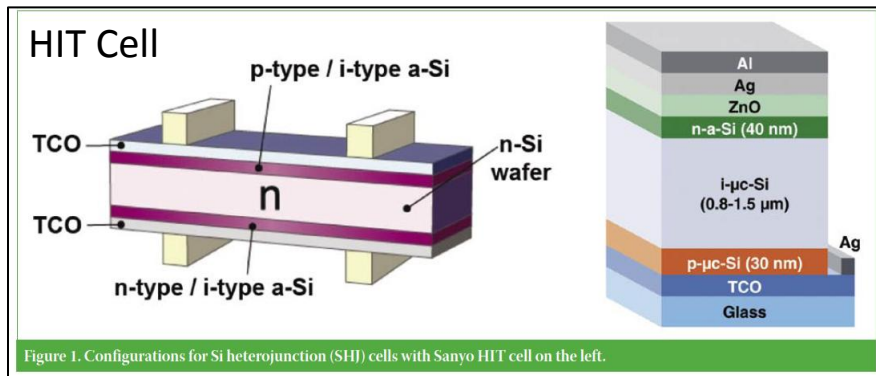
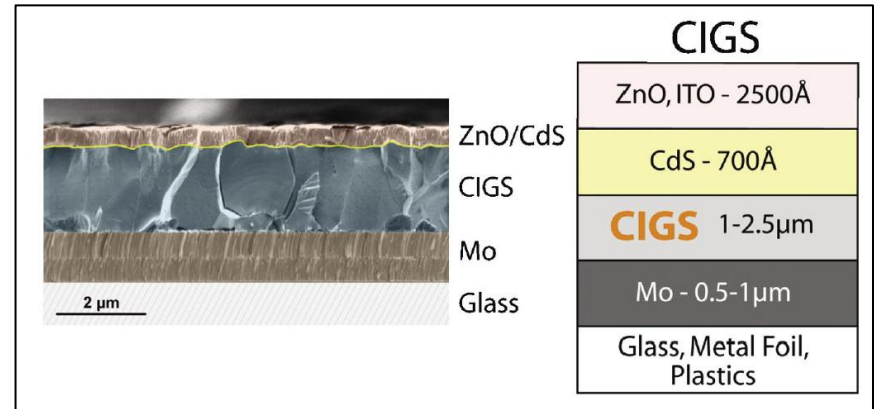
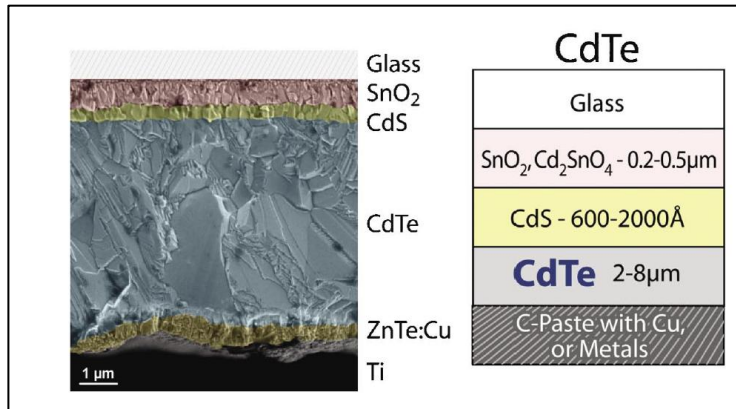
Impact of Electrical Loss Due to High Series Resistance (R_S) PV cells



Diode equation with R_S and R_{SH} :

$$I = I_L - I_0 \exp \left[\frac{q(V + IR_S)}{nkT} \right] - \frac{V + IR_S}{R_{SH}}$$

TCOs are Used in *All* PV devices



From:

Transparent conducting oxides for advanced photovoltaic applications

John D. Perkins & David S. Ginley, National Renewable Energy Laboratory, Golden, Colorado, USA

This paper first appeared in the third print edition of *Photovoltaics International* journal.

Long History of TCO R&D

“It is an object of this invention to provide on glass or other electrically non-conductive surfaces thin transparent coatings or films possessing the property of electrical conductivity, which coatings are clear, hard and tenacious and of uniform thickness; which are in intimate contact with the glass or other surface; and which will retain these properties under adverse conditions” – *Harold McMaster*

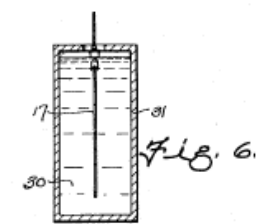
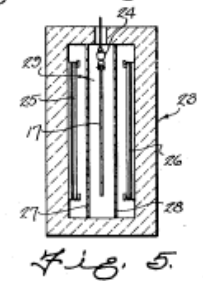
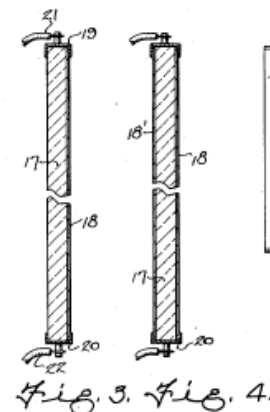
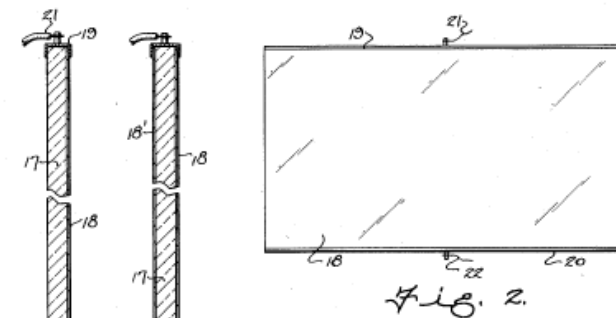
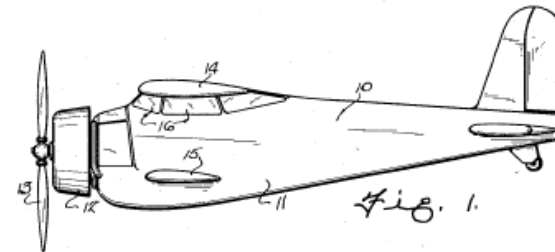
Oct. 21, 1947.

H. A. McMASTER

2,429,420

CONDUCTIVE COATING FOR GLASS AND METHOD OF APPLICATION

Filed Oct. 5, 1942

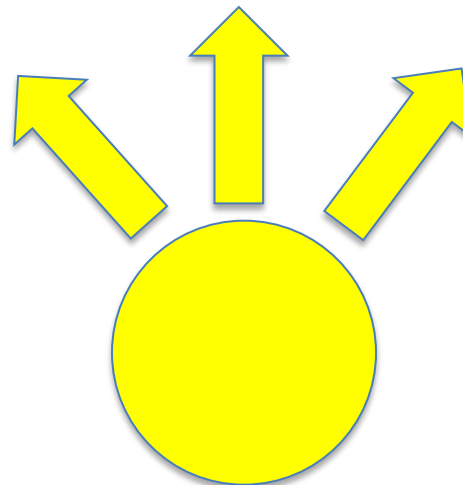
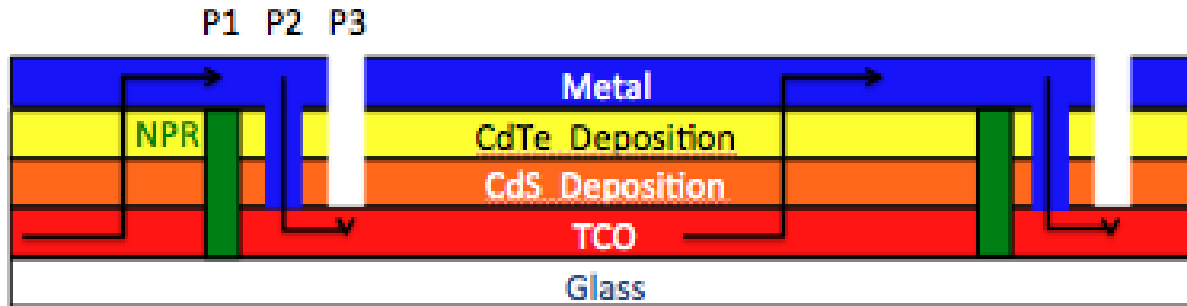


Inventor
HAROLD A. McMASTER

Frank Green
Attorney

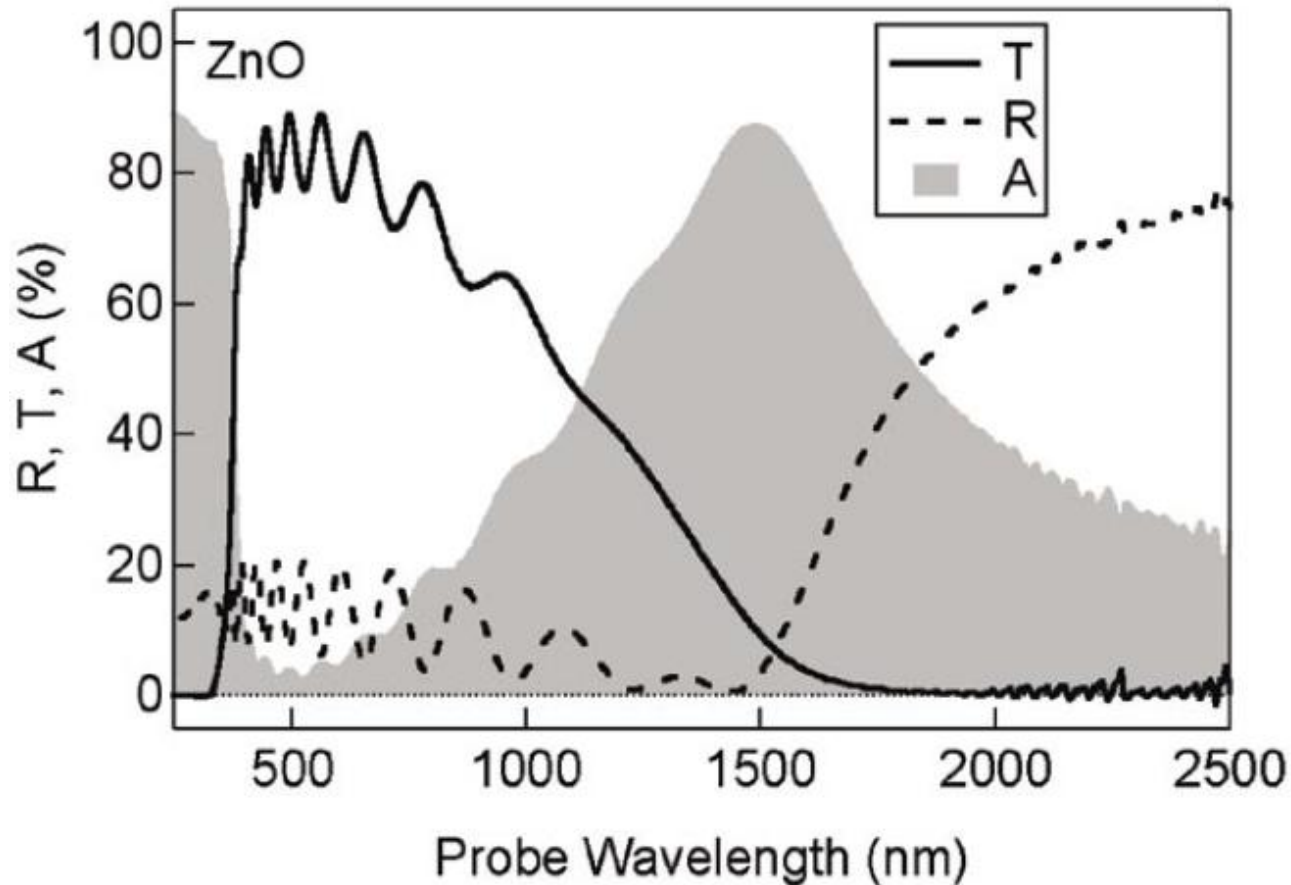
Monolithically Integrated TF Module

*The balance between electrical conductivity and optical transparency becomes even more important when current and photons are to be collected over large areas, as is the case in a module.**

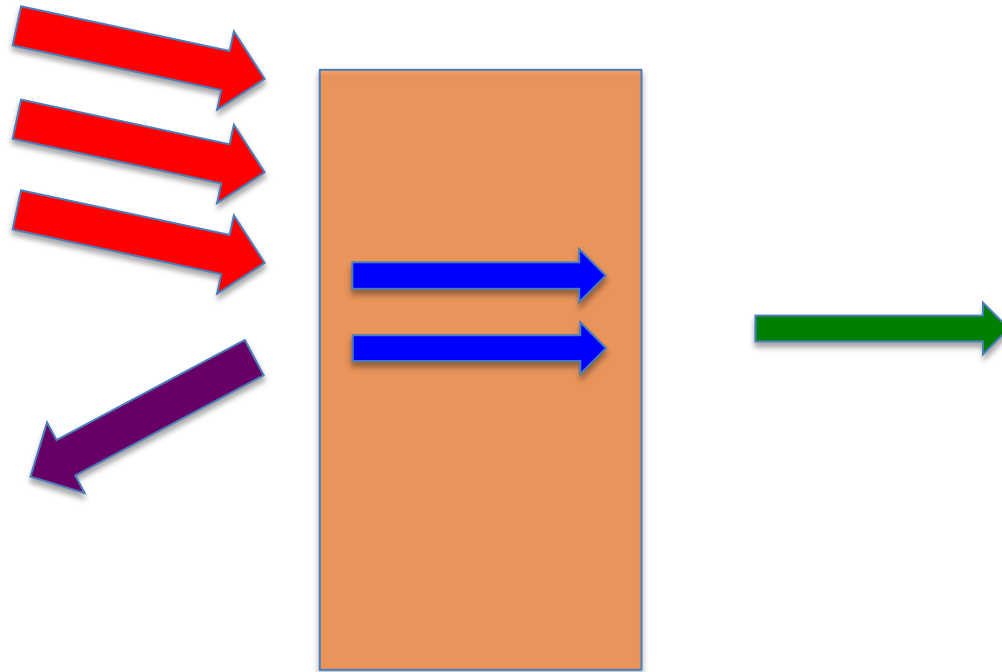


* Manufacturability is also a big concern!!

Typical Reflection, Transmission, and Absorption Data



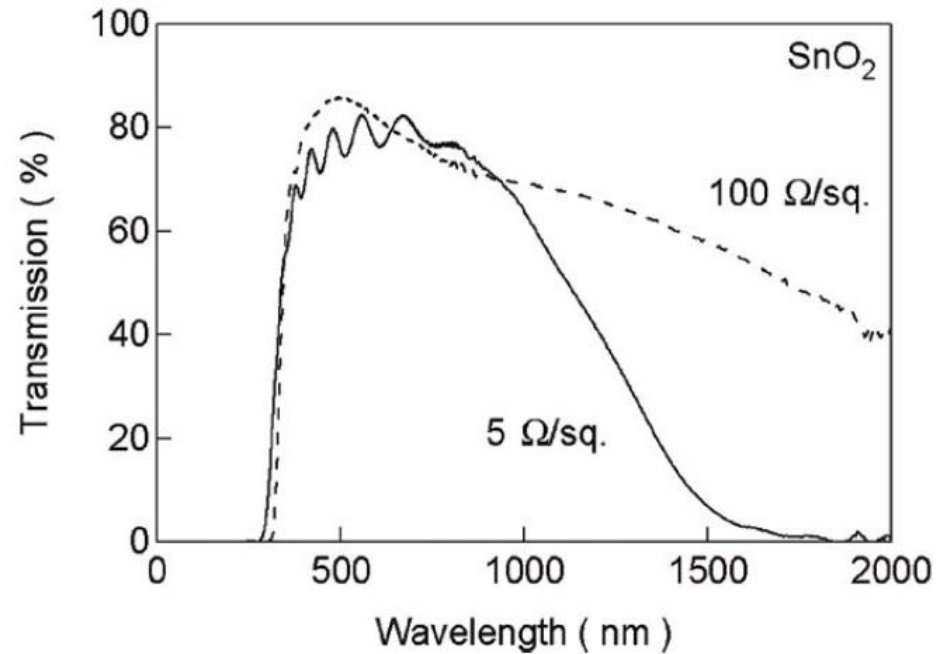
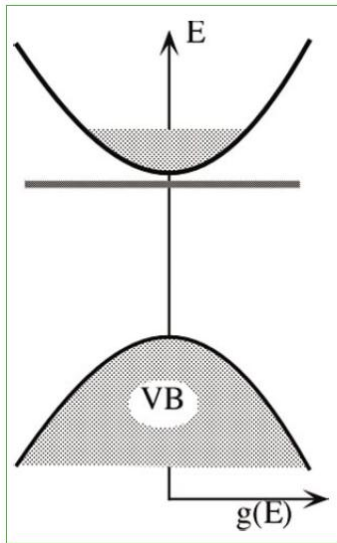
$$\text{Total Incident } (\lambda) = A(\lambda) + T(\lambda) + R(\lambda)$$



Conservation of Energy for each wavelength

Defect Equilibria and Doping in TCOs

- TCO materials are typically wide band gap oxides that are degeneratively doped via defect or substitutional chemistry.
- The trade off between electrical conductivity and transparency is due to the interplay between the electronic structure of the material and the doping.

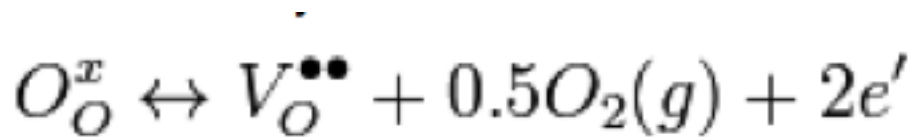
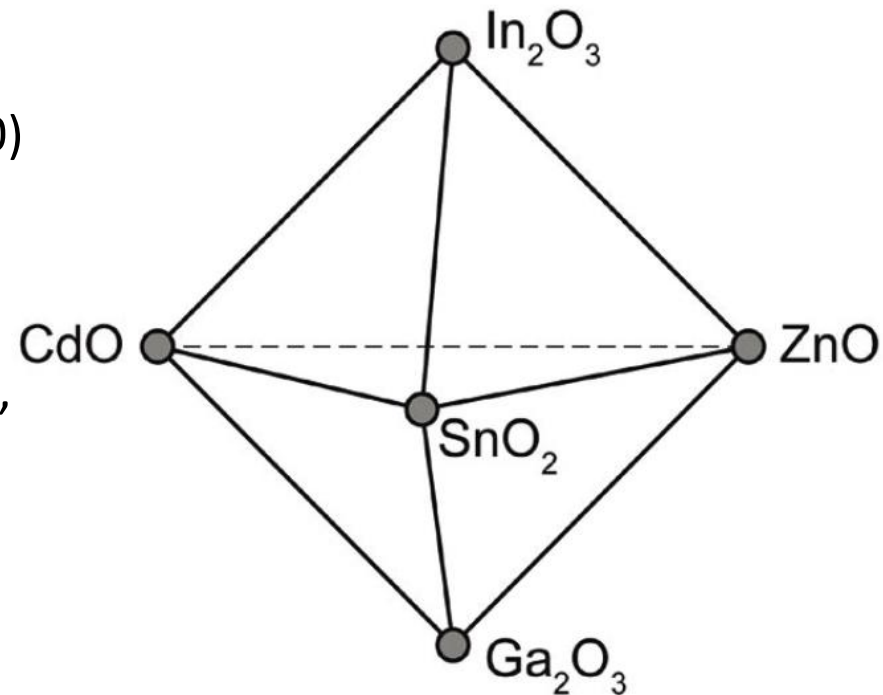


Phase Space for Engineering the Properties of TCOs

“Conventional” compositional space

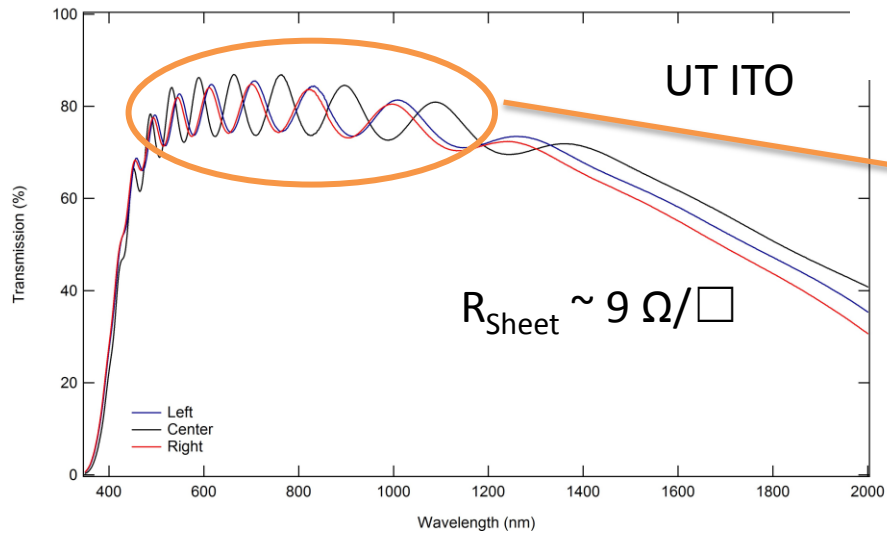
Additional Parameters for control:

- Compositional alloys (e.g. Cd_2SnO_4)
- Dopants on the anion sublattice (i.e. FTO)
- Dopants on the cation sublattice (e.g., ITO)
- Defect equilibria on oxygen sublattice
- New materials
- Nanomaterials (non-oxides, e.g. single-wall carbon nanotubes, metal nano wires, composites, etc.



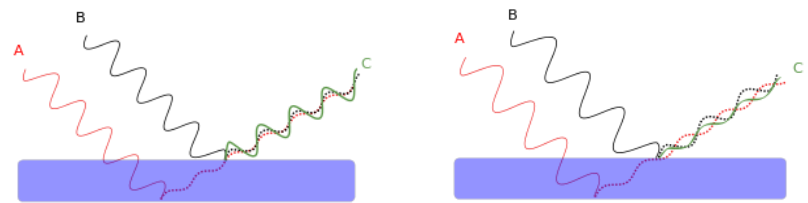
From: Perkins and Ginley

ITO – Tin doped Indium Oxide

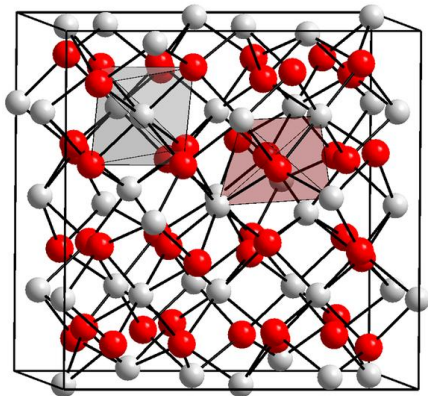
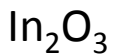


$$2n_{\text{coating}}d \cos(\theta_2) = m\lambda \quad \text{for constructive interference}$$

$$2n_{\text{coating}}d \cos(\theta_2) = \left(m - \frac{1}{2}\right) \lambda \quad \text{for destructive interference}$$



Courtesy of A. Phillips



2	13	14	15	16	17	18
He Helium 4.002602	B Boron 10.811	C Carbon 12.0107	N Nitrogen 14.0064	O Oxygen 15.9994	F Fluorine 18.9984032	Ne Neon 20.1797
Al Aluminum 26.9815386	Si Silicon 28.0855	P Phosphorus 30.973762	S Sulfur 32.06	Cl Chlorine 35.453	Ar Argon 39.948	Kr Krypton 83.798
In Indium 114.818	Sn Tin 118.710	Sb Antimony 121.757	Te Tellurium 127.6	I Iodine 126.905	Xe Xenon 131.29	Rn Radon (222.0176)
Tl Thallium 204.3833	Pb Lead 207.2	Bi Bismuth 208.9804	Po Polonium (209)	At Astatine (210)	Rn Radon (222.0176)	
Uut Ununtrium (261)	Uuq Ununquadium (269)	Uup Ununpentium (277)	Uuh Ununhexium (285)	Uus Ununseptium (293)	Uuo Ununoctium (304)	

Snell's Law and the Index of Refraction

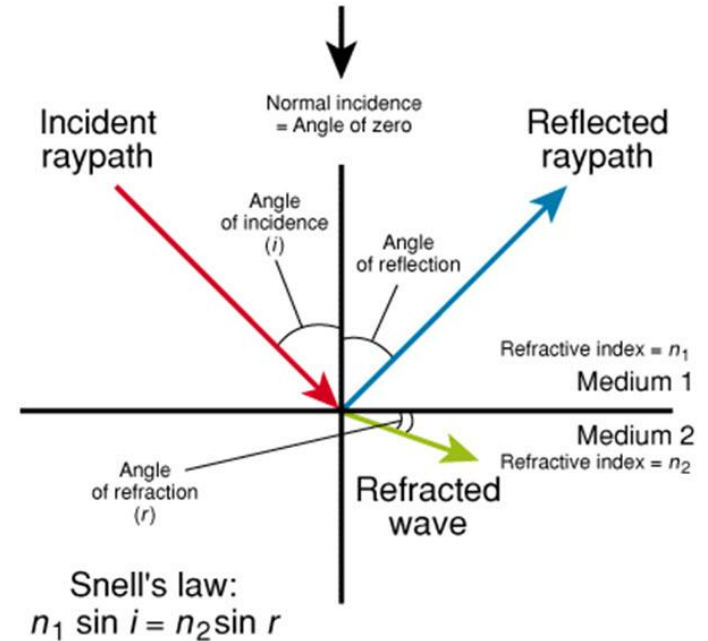
n , the Index of Refraction, *aka* Refractive Index

- Describes how light propagates in a medium.
- Is a dimensionless number.
- The speed of light in a medium is reduced:

$$v_{ph} = \frac{c}{n} \quad v = \frac{c}{\lambda}$$

$$\lambda = \frac{\lambda_0}{n}$$

Where λ_0 is the wavelength in vacuum



Although named after Dutch astronomer **Willebrord Snellius** (1580–1626), the law was first accurately described by the scientist **Ibn Sahl** at Baghdad court, when in 984 he used the law to derive lens shapes that focus light with no geometric aberrations in the manuscript *On Burning Mirrors and Lenses*

Absorption

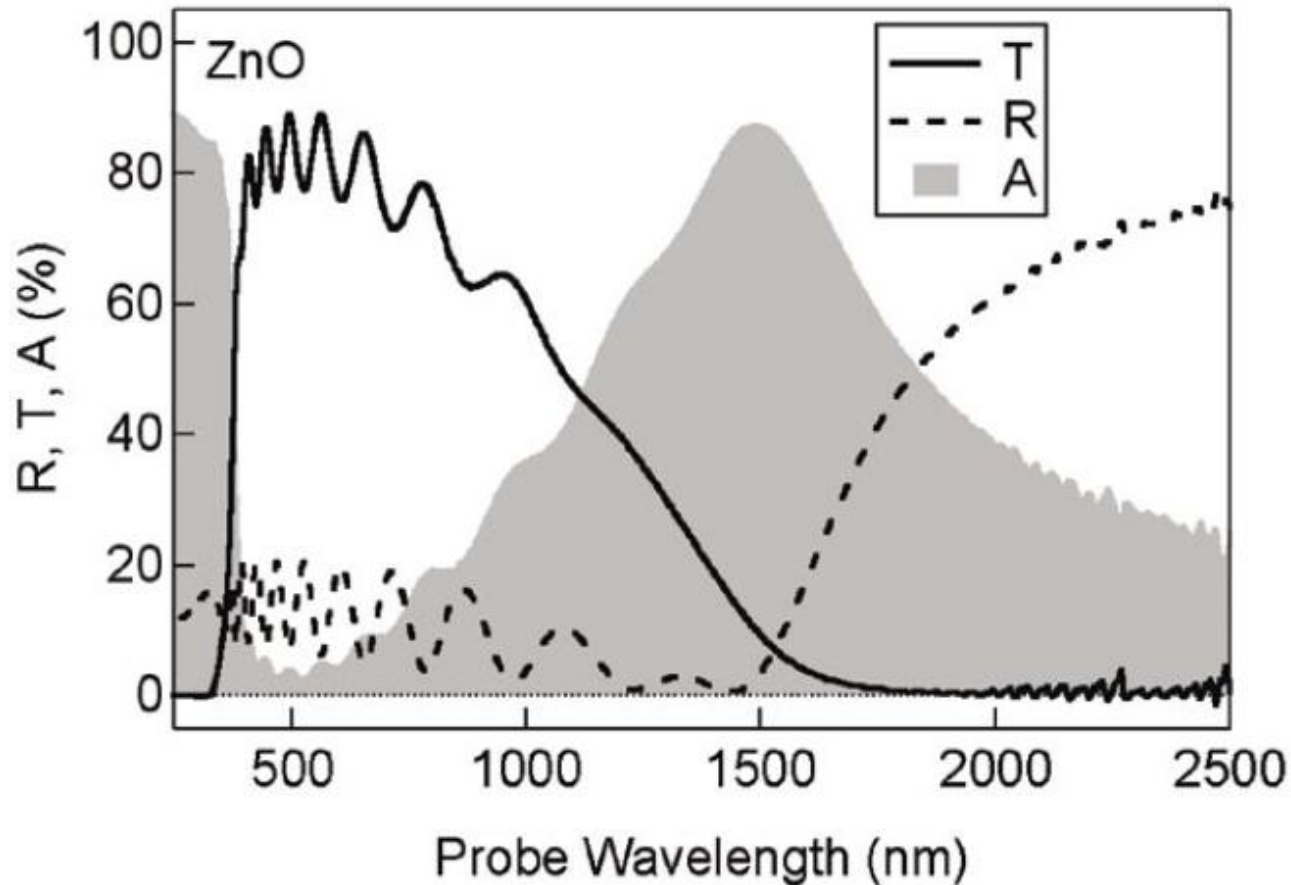
- Up to now, we have considered only the Index of Refraction, n .
- This is enough when there is no absorption (e.g., wide band gap oxides interacting with sub-band gap light).
- In general, we must consider refraction, reflection and absorption, and a complex index:

$$\tilde{n} = n + i\kappa$$

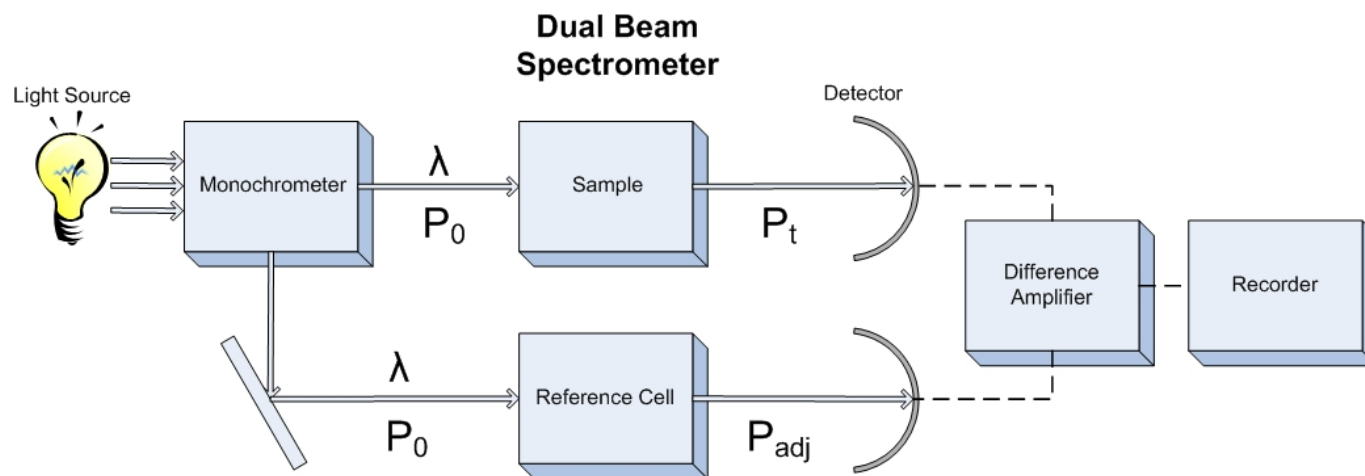
- Here, n is still the Index of Refraction, and reflects the phase speed of the light in the medium, but κ now refers to the amount of absorption loss.

$$\alpha = \frac{4\pi\kappa}{\lambda} \quad \frac{I}{I_0} = e^{-\alpha x}$$

Typical Reflection, Transmission, and Absorption Data



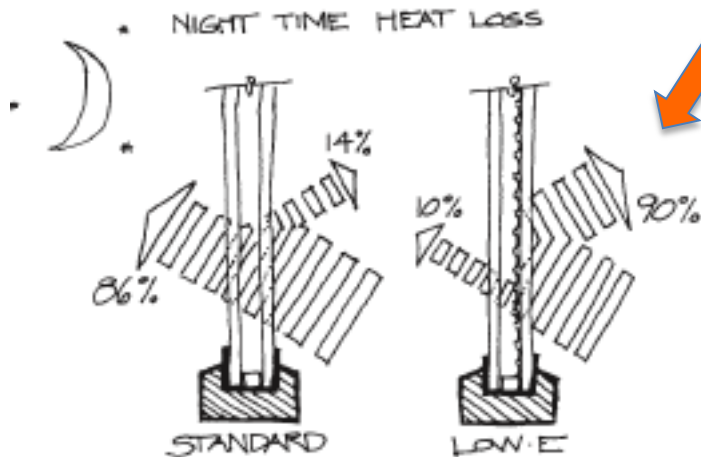
Conventional Dual Beam Spectrophotometer



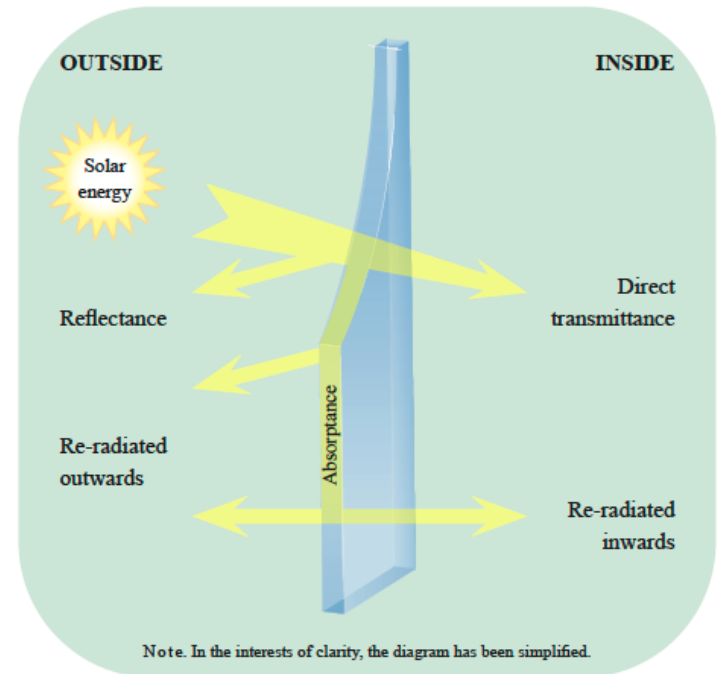
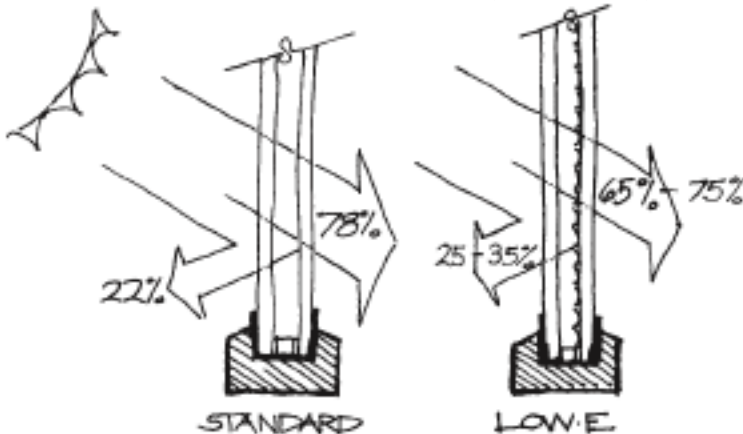
In this Lab, we are building a Single Beam Spectrophotometer

TCO Coatings on Glass Facilitate High Efficiency window technology

Reflection of long wavelength light at night is a big deal!



Reduction in Solar Passive Heat gain during the day



www.pilkington.com

“Consumer’s guide to buying energy-efficient windows and doors” by Canada’s Office of Energy Efficiency

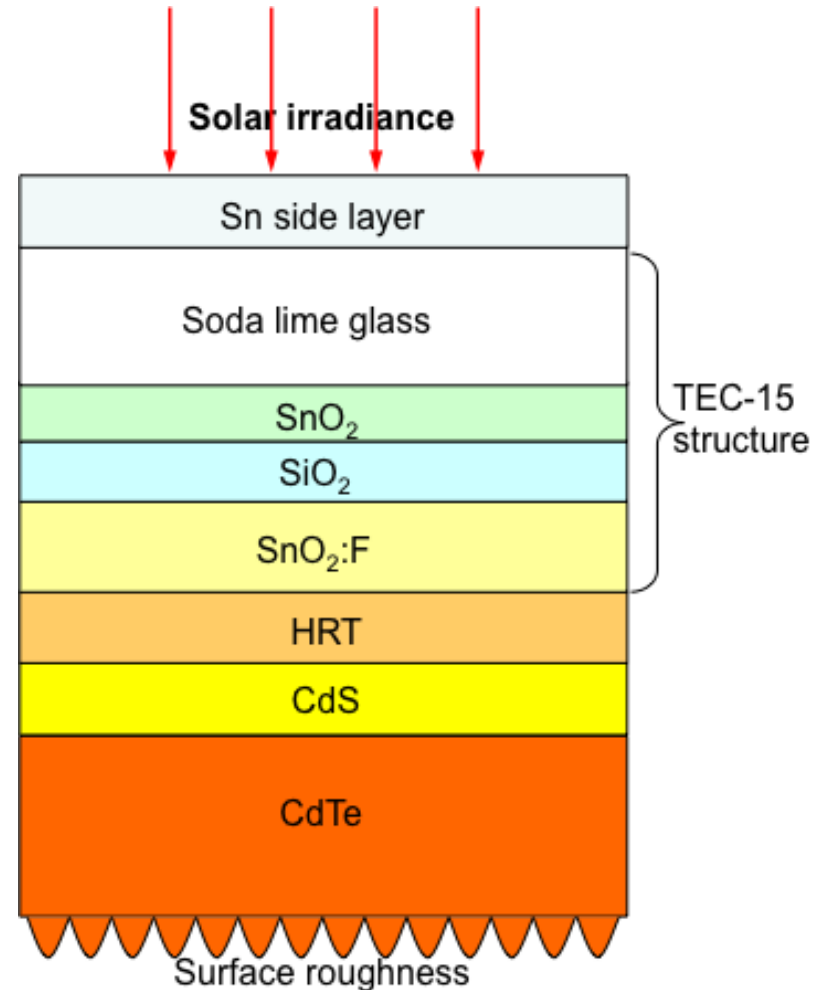
Learn about how a Float Line Works at:

<http://www.youtube.com/watch?v=OVokYKqWRZE>

TEC Coatings are Complex

The TEC-15 glass:

- Thick soda-lime float glass (3.2 mm)
- Thin SnO_2 layer ($\sim 300 \text{ \AA}$)
- SiO_2 layer ($\sim 200 \text{ \AA}$)
- $\text{SnO}_2:\text{F}$ layer ($\sim 3000 \text{ \AA}$)
- Thick HRT ($\sim 850 \text{ \AA}$)



Courtesy of Prakash Koirala

Different kinds of TEC products

TEC Glass™ portfolio

TEC 7

Offers the lowest resistivity value in the TEC Glass™ range. Combined with relatively low haze, it can be used for a wide range of applications including dye solar cells, electromagnetic shielding and thin film photovoltaics.

TEC 8

Designed for use specifically with amorphous silicon thin film photovoltaics. This product combines the low resistivity of **TEC 7** with a high haze coating required for good conversion efficiencies of amorphous silicon modules.

TEC 15

The best choice for applications requiring passive condensation control and thermal performance with low emissivity and clear color-neutral appearance.

TEC 35

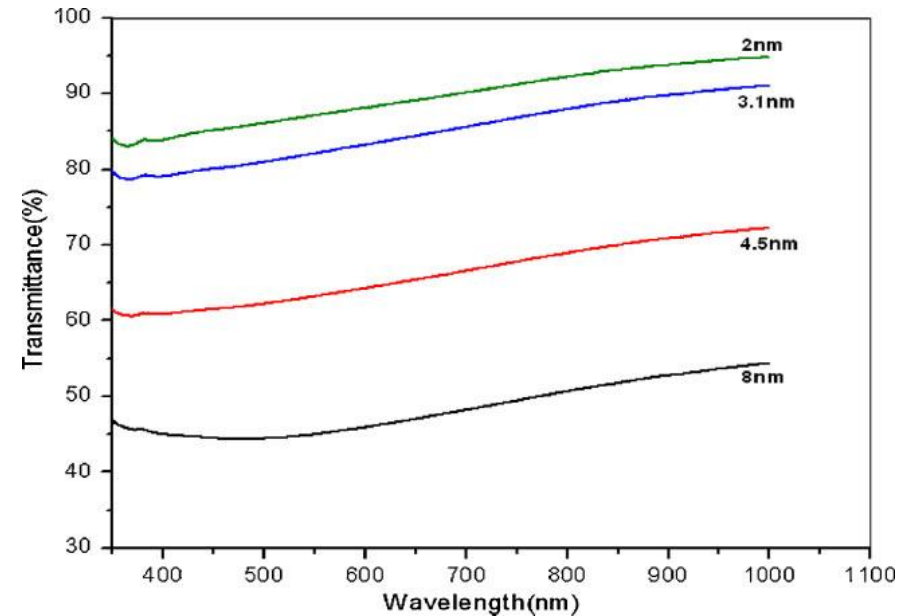
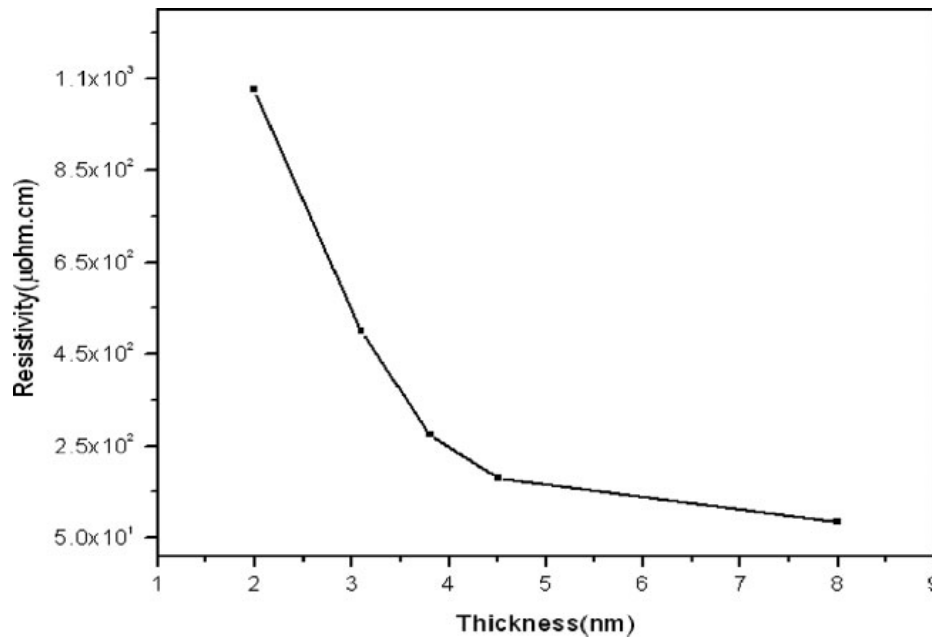
For use in heated glass applications, this product combines thermal control with superior electro-optical properties.

Ultrathin chromium transparent metal contacts by pulsed dc magnetron sputtering

K. V. Rajani^{*1}, S. Daniels¹, P. J. McNally², F. Olabanji Lucas², and M. M. Alam²

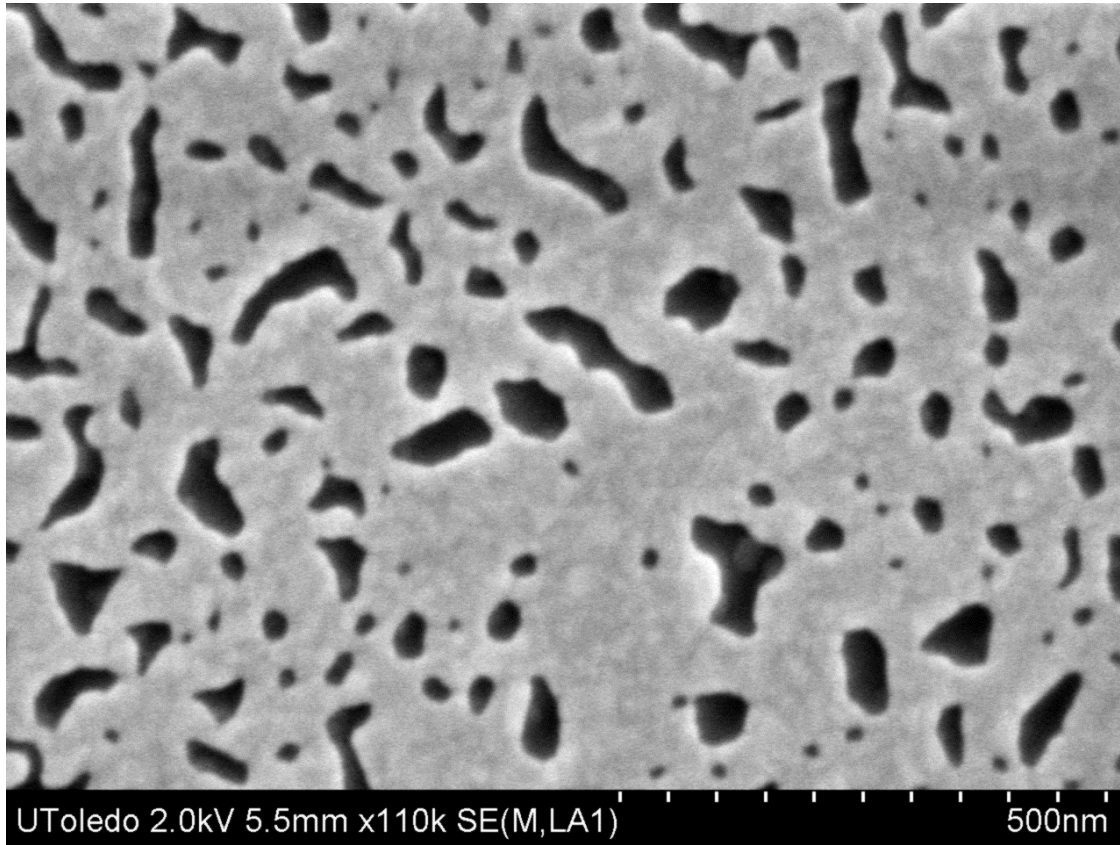
¹Nanomaterials Processing Laboratory, National Centre for Plasma Science and Technology (NCPST), School of Electronic Engineering, Dublin City University, Dublin 9, Ireland

Thin metal films can also be transparent



“The sheet resistance values corresponding to the 2, 3.1, 4.5 and 8 nm thick films are 5x10³, 1.6x10³, 4x10² and 1x10² Ω/□, respectively.”

Sheet Resistance – importance of film morphology



Scanning Electron Microscope (SEM) image of ~15 nm thick Au deposited by thermal evaporation.